

PI3B16215

**3.3V, 20-Bit** *NanoSwitch*<sup>™</sup>

# w/Precharged Outputs

## **Product Features**

- Near Zero Propagation Delay
- 5-ohm Switches Connect Between Two Ports
- Fast Switching Speed: 4.5ns max.
- B-Port Outputs are precharged by Bias Voltage to minimize signal distortion during live insertion
- Package options include:
  - 48-pin 150-mil wide plastic BQSOP (B)
  - -48-pin 240-mil wide plastic TSSOP (A)
  - -48-pin 300-mil wide plastic SSOP(V)

# Logic Block Diagram



### **Product Description**

Pericom Semiconductor's PI3B series of logic circuits are produced using the company's advanced submicron CMOS Technology. The PI3B16215 provides 20-bits of high-speed bus switching. The switches low ON-state resistance allows connections to be made with minimal propagation delay also precharges the B-port to a userselectable bias voltage (BIASV) to minimize live- insertion noise.

The device is organized as dual 10-bit bus switches with individual output-enable ( $\overline{OE}$ ) inputs. When  $\overline{OE}$  is LOW, the corresponding 10-bit bus switch is on and port A is connected to port B. When  $\overline{OE}$  is HIGH, the switch is open, a high-impedance state exists between the two ports, and port B is precharged to BIASV through the equivalent of a 10-kohm resistor.

 $\underline{To}$  ensure the high-impedance state on power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver connected to  $\overline{OE}$ .

# **Product Pin Configuration**

BIASV [	1 2	$\neg$	
		$\smile$	
	12		
1A1 [			47 20E
1A2 🗌			46 🛛 1B1
1A3 🗌			45 🛛 1B2
1A4 [	5		44 🛛 1B3
1A5 🗌	6		43 🛛 1B4
1A6 🗌	7		42 🛛 1B5
GND	8		41 🛛 GND
1A7 🗌	9		40 🛛 1B6
1A8 🗌	10		39 🗋 1B7
1A9 🗌	11	40 D'	38 🛛 1B8
1A10 🗌	12	48-Pin	37 🗋 1B9
2A1 🗌	13	A,B,V	36 🛛 1B10
2A2	14		35 🛛 2B1
Vcc E	15		34 🛛 2B2
2A3 🗌	16		33 🛛 2B3
GND [	17		32 🛛 GND
2A4 🗌	18		31 🗋 2B4
2A5 🗌	19		30 🛛 2B5
2A6 🗌	20		29 🛛 2B6
2A7 🕻	21		28 🛛 2B7
2A8 🗌	22		27 🛛 2B8
2A9 🗌	23		26 🛛 2B9
2A10	24		25 🛛 2B10

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#### **Maximum Ratings**

(Above which useful life may be impaired. For user guidelines, not tested
Storage Temperature Range, T <sub>STG</sub> 65°C to +150°C
Supply Voltage Range, $V_{CC}$ 0.5V to +4.6V
Bias Voltage Range, BIASV0.5V to +4.6V
Input Voltage Range0.5V to +4.6V
DC Output Current 120mA
Power Dissipation

#### Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

#### **Electrical Characteristics** (Over the Operating Range, $T_A = -40^{\circ}$ C to $+85^{\circ}$ C, $V_{CC} = 3.0$ V to 3.6V)

Parameter	Description	Test Conditions		Min.	Тур.	Max.	Units
BIASV	Bias Voltage			0		VCC	
V <sub>IH</sub>	High-Level Control Input Voltage	$V_{CC} = 2.7V$ to 3.6V		2			v
VIL	Low-Level Control Input Voltage	$V_{\rm CC} = 2.7 V$ to 3.6	$V_{CC} = 2.7V$ to 3.6V			0.8	
V <sub>IK</sub>	Clamp Diode Voltage	$V_{CC} = 3.0V$	$I_I = -18 \text{mA}$		-0.7	-1.2	]
II	Input Current	$V_{CC} = 3.6V$	$V_I = V_{CC}$ or GND			±5	
I <sub>OZH</sub>	High Impedance Output Current	$V_{CC} = 0$	$V_{\rm I} = V_{\rm O} = 0$ to 3.6V			10	μA
Io	Output Current	$V_{CC} = 3.0V$	BIASV = $2.4V, V_0 = 0$	0.15			mA
ICC	Quiescent Power Supply Current	$V_{CC} = 3.6V$	$I_0 = 0, V_I = V_{CC} \text{ or } GND$			10	
$\Delta I_{CC}^{(1)}$	Supply Current	$V_{\rm CC} = 3.6 V$	One Input at 3V, Other Inputs at V <sub>CC</sub> or GND			750	μA
CIN	Input Capacitance	$V_{\rm I} = 3.0 V \text{ or } 0$			3.0		"Г
C <sub>OFF</sub>	A/B Capacitance Switch Off	$V_{\rm O} = 3.0 V \text{ or } 0$	Switch Off		8.5		pF
R <sub>ON</sub> <sup>(2)</sup>	Switch On Resistance	$V_I = 0$	$I_I = 64 \text{mA}$		5	8	
			$I_I = 24 \text{mA}$		5	8	Ω
		$V_{I} = 2.4 V$	$I_I = 15 \text{mA}$		10	15	]

#### Notes:

1. This is the increase in supply current for each input ( $\overline{OE}$  only) that is at the specified voltage level rather than V<sub>CC</sub> or GND.

2. Measured by the voltage drop between the A and B terminals at the indicated current through the switch. On state resistance is determined by the lower of the voltages of the two (A or B) terminals.

#### **Truth Table**

ŌĒ	Function		
L	A port = B port		
Н	A port = Z, B Port = BIASV		

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#### PI3B16215 3.3V, 20-Bit *NanoSwitch*™ w/Precharged Outputs

# Switching Characteristics over Operating Range

(Switching characteristics over recommended operating free-air temperature range unless otherwise noted)

				$V_{CC} = 3.3V \pm 10\%$		
Parameter	Test Conditions	From (Input)	To (Output)	Min.	Max.	Units
$t_{PD}^{(1)}$		A or B	B or A		0.25	
t <sub>PZH</sub>	BIASV = GND				4.5	
t <sub>PZL</sub>	BIASV = 3V	- <del>OE</del>	A an D		4.5	ns
t <sub>PHZ</sub>	BIASV = GND	OE	A or B		5.0	
t <sub>PLZ</sub>	BIASV = 3V				5.0	

#### Note:

1. The propagation delay is the calculated RC time of the typical on-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

#### **Parameter Measurements** ( $V_{CC}$ =2.7 and 3.3V±10%)



#### Notes:

Figure 1. Load Circuit and Voltage Waveforms

- 1. CL includes probe and jig capacitance.
- 2. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control.
- Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- 3. All input impulses are supplied by generators having the following characteristics: PRR  $\leq$  MHz, Z<sub>O</sub> = 50 $\Omega$ , t<sub>R</sub>  $\leq$  2.5ns, t<sub>F</sub>  $\leq$  2.5ns.
- 4. The outputs are measured one at a time with one transition per measurement.
- 5. t<sub>TPZ</sub> and t<sub>PHZ</sub> are the same as t<sub>DIS</sub>
- 6.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{EN}$
- 7. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>PD</sub>

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### 48-Pin TSSOP (A) Package



# 48-Pin BQSOP (B) Package





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#### 48-Pin SSOP (V) Package



#### **Ordering Information**

Part	Pin - Package	Width	Temperature
PI3B16215A	48-TSSOP	240-mil	
PI3B16215B	48-BQSOP	150-mil	-40°C to +85°C
PI3B16215V	48-SSOP	300-mil	

# **Applications Information**

#### **Logic Inputs**

The logic control inputs can be driven up to +3.6V regardless of the supply voltage. For example, given a +3.3V supply, IN may be driven low to 0V and high to 3.6V. Driving IN Rail-to-Rail® minimizes power consumption.

#### Power-Supply Sequencing and Hot Plug Information

Proper power-supply sequencing is recommended for all CMOS devices. Always apply  $V_{CC}$  before applying  $V_{BIAS}$  and signals to input/output or control pins.

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